

# Industrial SD Card

## 3TE4

**Customer:** \_\_\_\_\_

**Customer**

**Part Number:** \_\_\_\_\_

**Innodisk**

**Part Number:** \_\_\_\_\_

**Innodisk**

**Model Name:** \_\_\_\_\_

**Date:** \_\_\_\_\_

<b>Innodisk Approver</b>	<b>Customer Approver</b>

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## REVISION HISTORY

Revision	Description	Date
Preliminary 0.1	First release	May, 2021
V1.0	Official release	Nov., 2021
V.1.1	Revised NAND Flash Memory information	Jan., 2022
V1.2	Operating temperature correction	Jul., 2022
V1.3	Add 112-L 3D TLC	Oct., 2022
V1.4	Update Product image	Mar., 2025
V1.5	Remove EOL items	Aug., 2025
V1.6	Update theory of operation	Dec., 2025
V1.7	Remove EOL items	Jan., 2026
V1.8	Remove SD 2.0 & SD 1.1	Jun., 2026

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# 1. Product Overview

## 1.1 Introduction of Innodisk Industrial SD 3TE4

Innodisk 3TE4 is an industrial-grade SD card solution with an integrated industrial controller, which is designed for embedded applications. With enhanced flash technologies and a powerful configurable LDPC ECC engine, SD 3TE4 can achieve high-speed data transfer rates.

Innodisk industrial SD 3TE4 provides a wide range of capacities from 64GB to 256GB with 3D TLC NAND Flash, and is fully compliant with SD 6.1 and SD 3.0 specifications.

Innodisk industrial SD 3TE4 are specifically designed for industrial PC and embedded applications for high performance. With its low power consumption and the above-mentioned features, Innodisk industrial SD 3TE4 can be applied for industrial automation, SBC (single-board computer), medical equipment, infotainment, and mobile applications.

## 1.2 Product View and Models

Innodisk Industrial SD 3TE4 is available from 32GB up to 256GB capacities within 3D TLC Flash IC.

[SD 3TE4 64GB](#)

[SD 3TE4 128GB](#)

[SD 3TE4 256GB](#)



**Figure 1: Innodisk Industrial SD 3TE4**

## 1.3 SD 6.1 Interface

Innodisk Industrial SD 3TE4 is compliant with SD 6.1/ SD 3.0 interface.

## 2. Product Specifications

### 2.1 Capacity and Device Parameters

Innodisk Industrial SD card device parameters are shown in Table 1.

**Table 1: Device parameters**

Capacity	LBA
64GB	122159104
128GB	244318208
256GB	488636416

### 2.2 Performance

Burst Transfer Rate: UHS-I (up to 104 MB/s in SD 3.0 SDR104)

**Table 2: Performance**

Capacity	64GB	128GB	256GB
<b>Speed Class</b>	10	10	10
<b>UHS Class</b>	U3	U3	U3
<b>Sequential Read (max.)</b>	90 MB/s	90 MB/s	90 MB/s
<b>Sequential Write (max.)</b>	40 MB/s	80 MB/s	80 MB/s
<b>4KB Random** Read (Q32T1)</b>	2,000 IOPS	2,000 IOPS	2,000 IOPS
<b>4KB Random** Write (Q32T1)</b>	800 IOPS	800 IOPS	800 IOPS

Note: \* Performance results are measured in Room Temperature with Out-of-Box devices and may vary depending on overall system setup.

Note: \*\*Performance results are based on CrystalDiskMark 6.0.2 with file size 1000M

**Table 3: Memory Card Speed Specification**

Minimum Sequential Write Speed	Speed Class	UHS Speed Class
<b>30 MB/s</b>		<b>Class 30 (U3)</b>
<b>10 MB/s</b>	<b>Class 10 (C10)</b>	<b>Class 10 (U1)</b>
<b>6 MB/s</b>	<b>Class 6 (C6)</b>	
<b>4 MB/s</b>	<b>Class 4 (C4)</b>	
<b>2 MB/s</b>	<b>Class 2 (C2)</b>	

## 2.3 Electrical Specifications

### 2.3.1 Power Requirement

**Table 4: Innodisk Industrial SD card Power Requirement**

Item	Symbol	Rating	Unit
Input voltage	V <sub>IN</sub>	2.7V~3.6V	V

### 2.3.2 Power Consumption

**Table 5: Power Consumption**

Mode	Power Consumption (W)
Read (rms)	0.5
Write (rms)	0.7
Peak (max)	1.3
Idle (rms)	0.0009

## 2.4 Environmental Specifications

### 2.4.1 Temperature Ranges

**Table 6: Temperature range for Industrial SD card**

Temperature	Range
Operating	Standard Grade: -25°C to +85°C
	Industrial Grade: -40°C to +85°C
Storage	-40°C to +85°C

### 2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

### 2.4.3 Shock and Vibration

**Table 7: Shock/Vibration Testing for Industrial SD card**

Reliability	Test Conditions	Reference Standards
Vibration	7 Hz to 2K Hz, 20G, 3 axes	IEC 60068-2-6
Mechanical Shock	Duration: 0.5ms, 1500 G, 3 axes	IEC 60068-2-27

### 2.4.4 Mean Time between Failures (MTBF)

Table 8 summarizes the MTBF prediction results for various Industrial SD card configurations. The analysis was performed using a RAM Commander™ failure rate prediction.

- **Failure Rate:** The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval

under stated condition.

- **Mean Time between Failures (MTBF):** A basic measure of reliability for repairable items: The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

**Table 8: Industrial SD card MTBF**

Product	Condition	MTBF (Hours)
Innodisk Industrial SD 3TE4	Telcordia SR-332 GB, 25°C	>3,000,000

## 2.5 CE and FCC Compatibility

Industrial SD card conforms to CE and FCC requirements.

## 2.6 RoHS Compliance

Industrial SD card is fully compliant with RoHS directive.

## 2.7 Reliability

Parameter	Value
Read Cycles	Unlimited Read Cycles
Flash endurance	3,000 P/E cycles
Wear-Leveling Algorithm	Support
Bad Blocks Management	Support
Error Correct Code	Support
<b>TBW* (Total Bytes Written) Unit:TB</b>	
<b>Capacity</b>	<b>Sequential workload</b>
64GB	170.45
128GB	340.90
256GB	681.81
*Note: Sequential: Mainly sequential write, tested by Vdbench.	

## 2.8 Transfer Mode

Industrial SD 3TE4 support following transfer mode:

SD 6.1 / SD 3.0

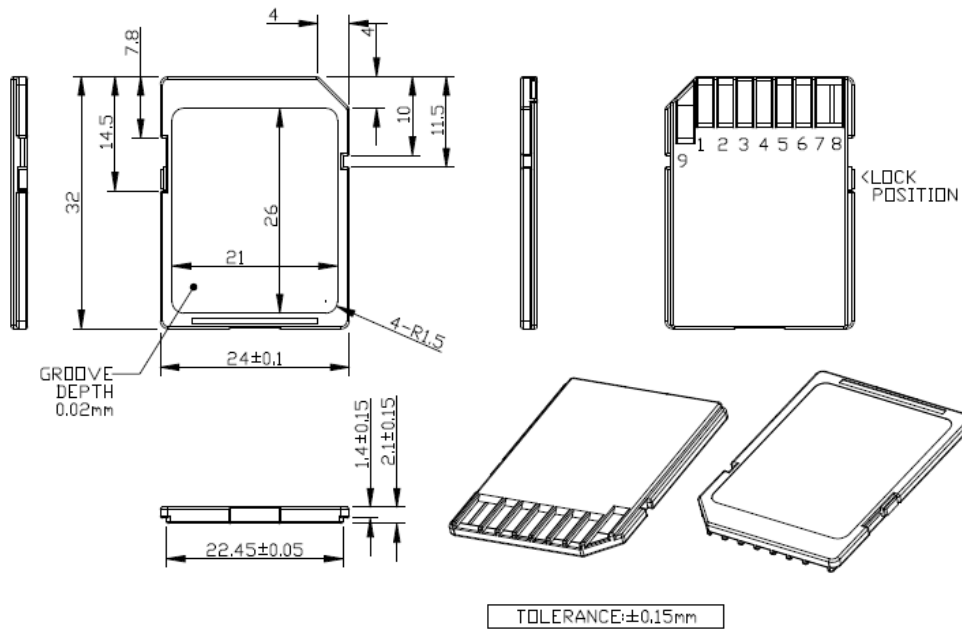
## 2.9 Pin Assignment

Innodisk Industrial SD 3TE4 compliant with standard SD SPEC., please refer to Table 9 for pin assignment.

**Table 9. SD card Pin Assignment**

Pin #	SD Mode			SPI Mode		
	Name	Type <sup>1</sup>	Description	Name	Type <sup>1</sup>	Description
1	CD/DAT3 <sup>2</sup>	I/O/PP <sup>3</sup>	Card Detect/Data Line [Bit 3]	CS	I <sup>3</sup>	Chip Select (Neg. True)
2	CMD	I/O/PP	Command/Response	DI	I	Data In
3	V <sub>SS1</sub>	S	Supply voltage ground	V <sub>SS</sub>	S	Supply voltage ground
4	V <sub>DD</sub>	S	Supply voltage	V <sub>DD</sub>	S	Supply voltage
5	CLK	I	Clock	SCLK	I	Clock
6	V <sub>SS2</sub>	S	Supply voltage ground	V <sub>SS2</sub>	S	Supply voltage ground
7	DAT0	I/O/PP	Data Line [Bit 0]	DO	O/PP	Data Out
8	DAT1 <sup>4</sup>	I/O/PP	Data Line [Bit 1]	RSV		
9	DAT2 <sup>5</sup>	I/O/PP	Data Line [Bit 2]	RSV		

## 2.10 Mechanical Dimensions



## 2.11 Assembly Weight

An Innodisk Industrial SD card 3.0 within 3D TLC flash ICs, 128GB's weight is 2 grams approx.

## 2.12 Seek Time

Innodisk Industrial SD card is not a magnetic rotating design. There is no seek or rotational latency required.

## 2.13 Hot Plug

The SD card support hot plug function and can be removed or plugged-in during operation.

## 2.14 NAND Flash Memory

Innodisk Industrial SD 3TE4 uses 3D TLC NAND flash memory, which is non-volatility, high reliability and high-speed memory storage.

## 2.15 Card Identification Register

The Card IDentification (CID) register is 128 bits wide. It contains the card identification information used during the card identification phase. Every individual flash card shall have a unique identification number. The structure of the CID register is defined in the following table.

**Table 10 Innodisk Industrial SD Card CID Table**

CID bit	Width	Name	Field
[127:120]	8	Manufacturer ID	MID
[119:104]	16	OEM/Application ID	OID
[103:64]	40	Product Name	PNM
[63:56]	8	Product Revision	PRV
[55:24]	32	Product Serial Number	PSN
[23:20]	4	Reserved	---
[19:8]	12	Manufacturing Date	MDT
[7:1]	7	CRC7 check sum	CRC
[0]	1	Not used, always '1'	---

## 2.16 SMART List

**Table 11.SMART List**

Offset	Byte Count	Attribute Name	Description
0x000	16	Reserved for Unique ID/Setting	Reserved for Unique ID/Setting
0x010	1	Bus Width	00h: 1 bit width 10h: 4 bit width
0x011	1	Secured Mode	00h: Not in the secured mode 01h: In secured mode
0x012	1	Speed Class	00h: Class 0 01h: Class 2 02h: Class 4 03h: Class 6 04h: Class 10
0x013	1	UHS Speed Grade	00h: Less than 10MB/sec 01h: 10MB/sec and above 02h: Reserved 03h: 30MB/sec and above
0x014	4	Protected Area Size	Protected Area Size (Bytes)

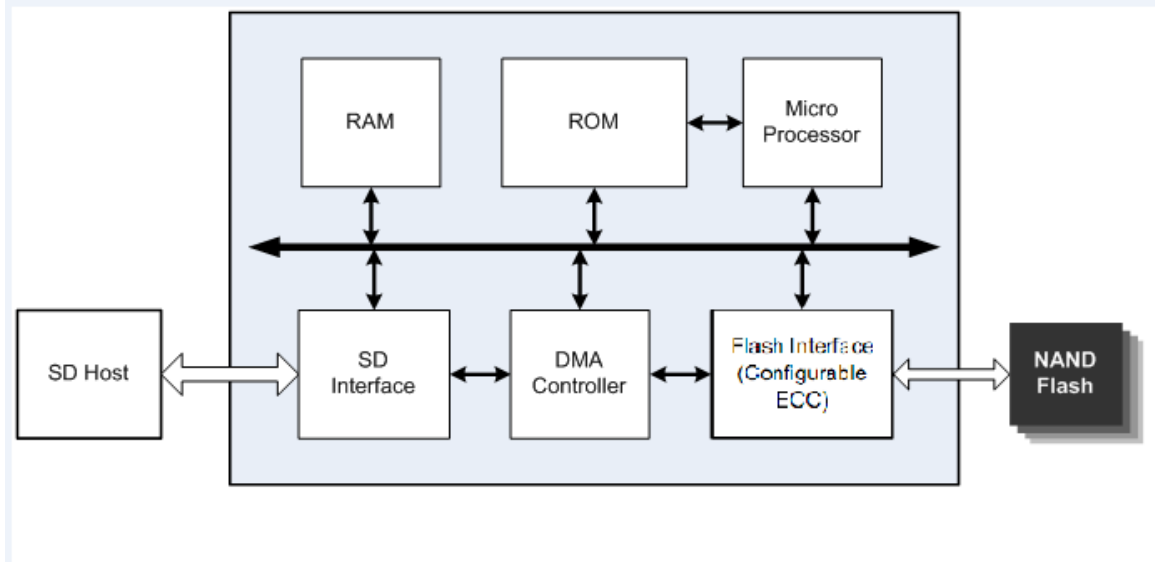
0x018	2	Original Bad Block Count	Original Bad Block Count
0x01A	1	RTBB Count	Run-time Bad Block Count
0x01B	1	Total SLC Spare Count	Total SLC Spare Block Count
0x01C	4	Reserved	Reserved
0x020	4	Min. Erase Count (Data Block)	Minimum Erase Count (Data Block)(TLC Block)
0x024	4	Max. Erase Count (Data Block)	Maximum Erase Count (Data Block)(TLC Block)
0x028	4	Total Erase Count (Data Block)	Total Erase Count (Data Block)(TLC Block)
0x02C	4	Avg. Erase Count (Data Block)	Average Erase Count (Data Block)(TLC Block)
0x030	4	Min. Erase Count (System Table Block)	Minimum Erase Count (System Table Block)(SLC Block)
0x034	4	Max. Erase Count (System Table Block)	Maximum Erase Count (System Table Block)(SLC Block)
0x038	4	Total Erase Count (System Table Block)	Total Erase Count (System Table Block)(SLC Block)
0x03C	4	Avg. Erase Count (System Table Block)	Average Erase Count (System Table Block)(SLC Block)
0x040	4	Raw Card Capacity	Raw Card Capacity (MB)
0x044	2	NAND P/E Cycle	NAND P/E Cycle (unit : 100 times)(TLC Block)
0x046	1	Card Life (%)	Remaining Card Life (%) = (NAND P/E Cycle - Avg. Erase Count (MLC or TLC))/NAND P/E Cycle (TLC Block)
0x047	1	Current SD Card Speed Mode	0x00: Default speed 0x01: High speed mode  0x10: SDR12 0x11: SDR25 0x12: SDR50 0x14: DDR50

			0x18: SDR104
0x048	4	Total Write CRC Count	Total Write CRC Count
0x04C	4	Power On/Off Count	Power On/Off Count
0x050	6	NAND Flash ID	NAND Flash ID (6 Bytes max.)(Only read flash ID for CE0)
0x056	1	MID	MID
0x057	1	Group Number	Group Number, ex. x4 with 4-way, group number=1, x4 with 2-way, group number=2
0x058	8	SMI SD Controller P/N	SMI SD Controller P/N (e.g. SM2706)
0x060	2	Read Claim Count (TLC Block)	Read Claim Count (Data on TLC Block) Host reads data on TLC Block and needs soft-decode case
0x062	2	Read Claim Count (SLC Block)	Read Claim Count (Data on SLC Block) Host reads data on SLC Block and needs soft-decode case
0x064	2	Firmware Block Refresh Counter	ISP Block refresh counter
0x066	2	Reserved	Reserved Area
0x068	4	TLC Read Count Threshold	TLC Read Count Threshold ( unit : 100 times )
0x06C	4	SLC Read Count Threshold	SLC Read Count Threshold ( unit : 100 times )
0x070	16	First TLC for each group	First TLC Block for each group
0x080	6	SD Firmware Version	SD Firmware Version (e.g. R0321x)
0x086	2	Reserved	Reserved Area
0x088	4	Data Refresh Count (TLC Block)	Data Refresh Count (TLC Block) Host reads data on TLC Block and read count is over TLC read count threshold case
0x08C	4	Data Refresh Count (SLC Block)	Data Refresh Count (SLC Block) Host reads data on SLC Block and read count is over SLC read count threshold case
0x090	16	CID Register	CID Register

# 3. Theory of Operation

## 3.1 Overview

Figure 2 shows the operation of Innodisk Industrial SD 3TE4 from the system level, including the major hardware blocks.



**Figure 2: Innodisk Industrial SD 3TE4 Block Diagram**

Innodisk Industrial SD 3TE4 integrates a SD 3.0 controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard SD interface.

## 3.2 SD 3.0 Controller

Innodisk Industrial SD 3TE4 is designed with a SD 3.0 controller, which has single channel for flash interface.

## 3.3 Error Detection and Correction

Innidisk SD 3TE4 is designed with hardware LDPC ECC engine with hard-decision and soft-decision decoding. Low-density parity-check (LDPC) codes have excellent error correcting performance close to the Shannon limit when decoded with the belief-propagation (BP) algorithm using soft-decision information.

## 3.4 Wear-Leveling

Flash memory can be erased within a limited number of times. This number is called the **erase cycle limit** or **write endurance limit** and is defined by the flash array vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk Industrial SD 3TE4 uses a global wear-leveling algorithm to ensure that consecutive writes of a specific sector are not written physically to the same page/block in the flash. This spreads flash media usage evenly across all pages, thereby extending flash lifetime.

### **3.5 Bad Blocks Management**

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the product is shipped, or may develop during the life time of the SD card. When the Bad Blocks is detected, it will be flagged, and not be used anymore. The SD card implement Bad Blocks management, Bad Blocks replacement, Error Correct Code to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

### **3.6 Garbage Collection**

Garbage collection is used to maintain data consistency and perform continual data cleansing on SD card. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SD's speed and lifespan.

### **3.7 Power cycling**

Innodisk's SD/MSDs provide the complete data protection mechanism during every abnormal power shutdown situation. Such as: power failure at programming data, updating system tables, erasing blocks, etc. The mechanism can maintain the data correctness and increase the reliability of the data stored in the NAND Flash memory.

## 4. Installation Requirements

### 4.1 Industrial SD card Pin Directions

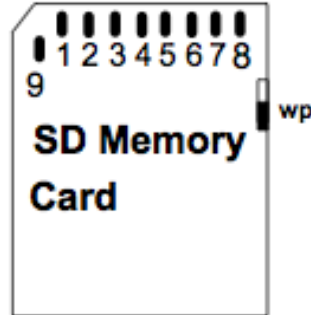


Figure 3: Signal Segment and Power Segment

### 4.2 Device Drive

No additional device drives are required.

## 5. Part Number Rule

CODE	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20
	D	E	S	D	C	-	A	2	8	S	0	6	K	E	1	S	L	-	X	X
<b>Definition</b>																				
<b>Code 1<sup>st</sup> (Disk)</b>										<b>Code 13<sup>th</sup> (Flash Mode)</b>										
D: Disk										K: 112 Layers 3D TLC										
<b>Code 2<sup>nd</sup> ~ 5<sup>th</sup> (Form Factor)</b>										<b>Code 14<sup>th</sup> (Operation Temperature)</b>										
ESDC: Industrial SD Card										E: Extended Grade (-25°C~ +85°C)										
										W: Industrial Grade (-40°C~ +85°C)										
<b>Code 7<sup>th</sup> ~9<sup>th</sup> (Capacity)</b>										<b>Code 15<sup>th</sup> (Internal control)</b>										
64G: 64GB										1: Product version										
A28: 128GB										<b>Code 16<sup>th</sup> (Channel of data transfer)</b>										
B56: 256GB										S: Single Channel										
										<b>Code 17<sup>th</sup> (Flash Type)</b>										
										L: Innodisk 3D TLC										
<b>Code 10<sup>th</sup> ~12<sup>th</sup> (Controller)</b>										<b>Code 19<sup>th</sup>~20<sup>th</sup> (Customized Code)</b>										
S06: 3TE4 Series																				